## NSN 5961-01-346-2338

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-346-2338 **Inclosure Material:** Metal **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205af **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 drain to gate voltage and -100.0 drain to source voltage and 20.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 6.50 amperes drain current **Power Rating Per Characteristic:** 25.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 07187-8507002 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/564 government specification Shelf Life: N/a **Unit Of Measure:** 

Fiig: A110a0

No

**Demilitarization:**